

Series PVI-N & PbF

Photovoltaic Isolator
Single and Dual Channel
5-10 Volt Output

General Description

The PVI Series Photovoltaic Isolator generates an electrically isolated DC voltage upon receipt of a DC input signal. It is capable of directly driving gates of power MOSFETs or IGBTs. It utilizes a monolithic integrated circuit photovoltaic generator of novel construction as its output. The output is controlled by radiation from a GaAlAs light emitting diode (LED), which is optically isolated from the photovoltaic generator.

The PVI Series is ideally suited for applications requiring high-current and/or high-voltage switching with optical isolation between the low-level driving circuitry and high-energy or high-voltage load circuits. It can be used for directly driving gates of power MOSFETs. The dual-channel device allows its outputs to drive independent discrete power MOSFETs, or be connected in parallel or in series to provide higher current drive for power MOSFETs or higher voltage drive for IGBTs. The PVI Series Photovoltaic isolators employ fast turn-off circuitry.

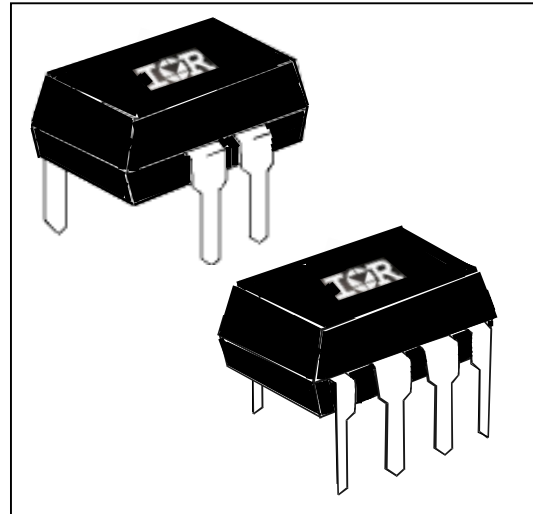
These PVI Series Photovoltaic Isolators are packaged in 8-pin, molded DIP packages and available with either thru-hole or surface-mount ("gull-wing") leads, in plastic shipping tubes.

Applications

- Load Distribution
- Industrial Controls
- Current-to-Voltage Conversion
- Custom Solid-State Relay

Features

- Isolated Voltage Source
- Monolithic Construction
- Up to 8 μ A Output
- Single or Dual Output
- Solid-State Reliability



Part Identification

PVI1050N & PbF	thru-hole
PVI5050N & PbF	
PVI5080N & PbF	
PVI1050NS & PbF	surface-mount (gull-wing)
PVI5050NS & PbF	
PVI5080NS & PbF	

Electrical Specifications ($-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ unless otherwise specified)

INPUT CHARACTERISTICS	PVI Series	Units
Input Current Range (see figure 4)	2.0 to 50	mA (DC)
Maximum Forward Voltage Drop @ 10mA, 25°C (see figure 5)	1.4	V (DC)
Maximum Reverse Voltage	6.0	V(DC)
Maximum Reverse Current @ -6.0V (DC), 25°C	100	$\mu\text{A(DC)}$
Maximum Pulsed Input Current @ 25°C (see figure 6)	1.0	A(peak)

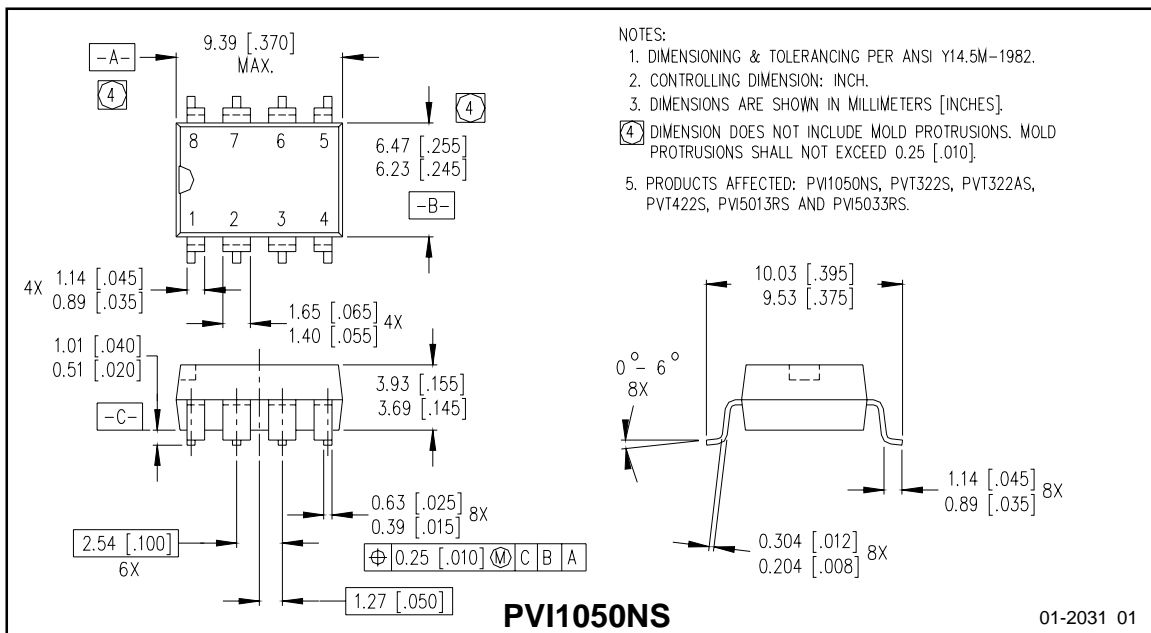
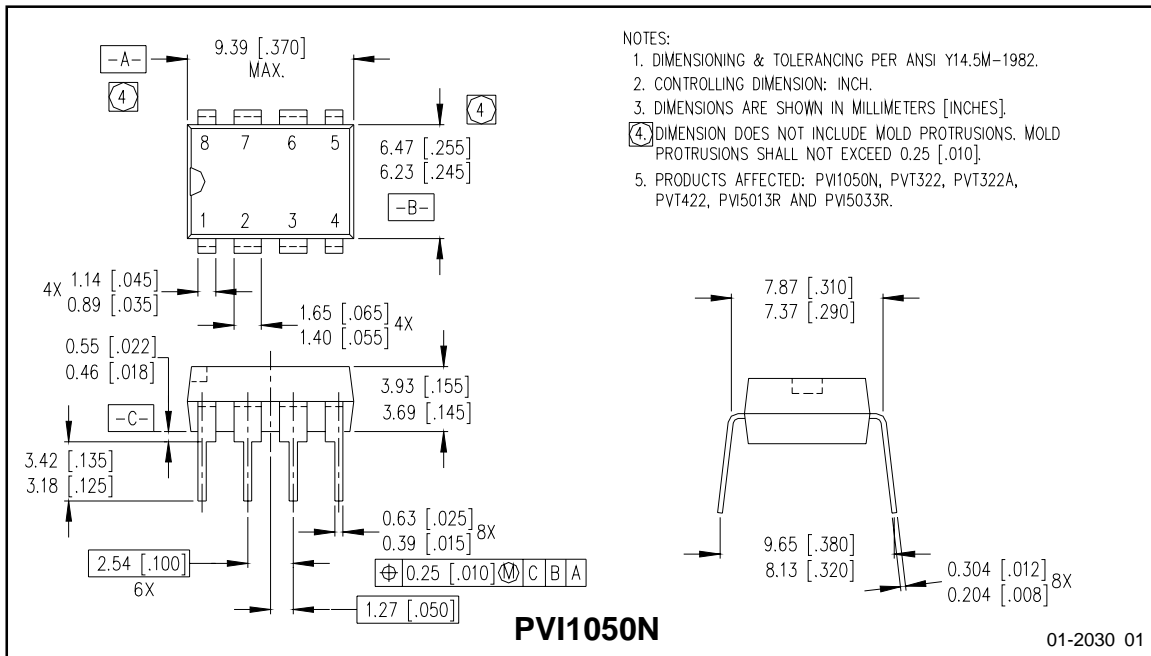
OUTPUT CHARACTERISTICS	PVI Series	Units
Maximum Forward Voltage @ 10 μA	8.0 per channel	$V_{(DC)}$
Maximum Reverse Current @ -10VDC	10	$\mu\text{A(DC)}$

COUPLED CHARACTERISTICS	PVI5050N	PVI5080N	PVI1050N	Units
Minimum Open Circuit Voltage @ ILED = 10mA, 25°C, $R_L = >10\text{M}\Omega$ (see figures 1 to 2)	5.0		5.0/channel 10 series	V (DC)
Minimum Short Circuit Current @ ILED = 10mA, 25°C (see figures 1 to 2)	5.0	8.0	5.0 /channel 10 parallel	$\mu\text{A (DC)}$
Maximum Capacitance (Input/Output)	1.0		2.0	pF
Maximum Ton Time @ ILED=10mA, CLOAD=10pF (See Figure7)				μS
$R_L > 20\text{M}\Omega$	300			μS
$R_L = 10\text{M}\Omega$	160			μS
$R_L = 4.7\text{M}\Omega$	90			μS
Maximum Toff Time @ ILED=10mA, CLOAD=10pF (See Figure7)	220			μS

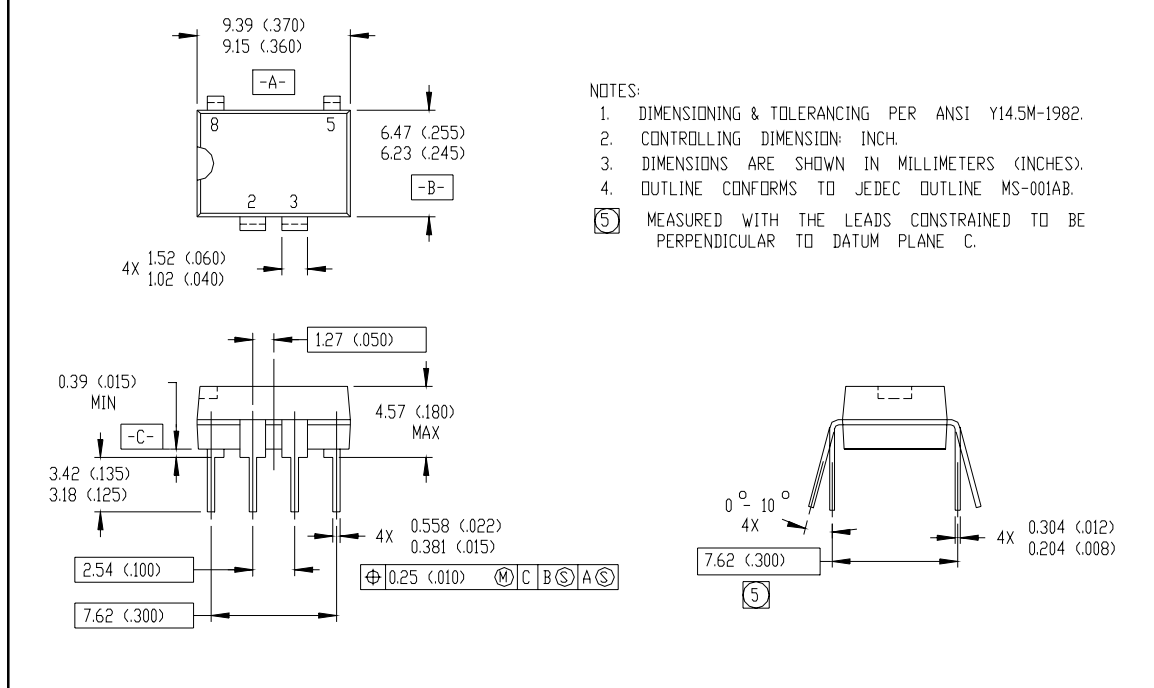
GENERAL CHARACTERISTICS	PVI5050N/5080N	PVI1050N	Units
Min. Dielectric Strength, Input-Output	4000	2500	V_{RMS}
Min. Dielectric Strength, Output-to-Output	1200		V_{DC}
Min. Insulation Resistance, Input-to-Output @ $T_A = +25^{\circ}\text{C}$, 50%RH, 100VDC	10^{12}		Ω
Max. Pin Soldering Temperature (10 seconds max.)	+260		$^{\circ}\text{C}$
Ambient Temperature Range: Operating	-40 to +85		$^{\circ}\text{C}$
Storage	-40 to +125		$^{\circ}\text{C}$

International Rectifier does not recommend the use of this product in aerospace, avionics, military or life support applications. Users of this International Rectifier product in such applications assume all risks of such use and indemnify International Rectifier against all damages resulting from such use.

Case Outlines

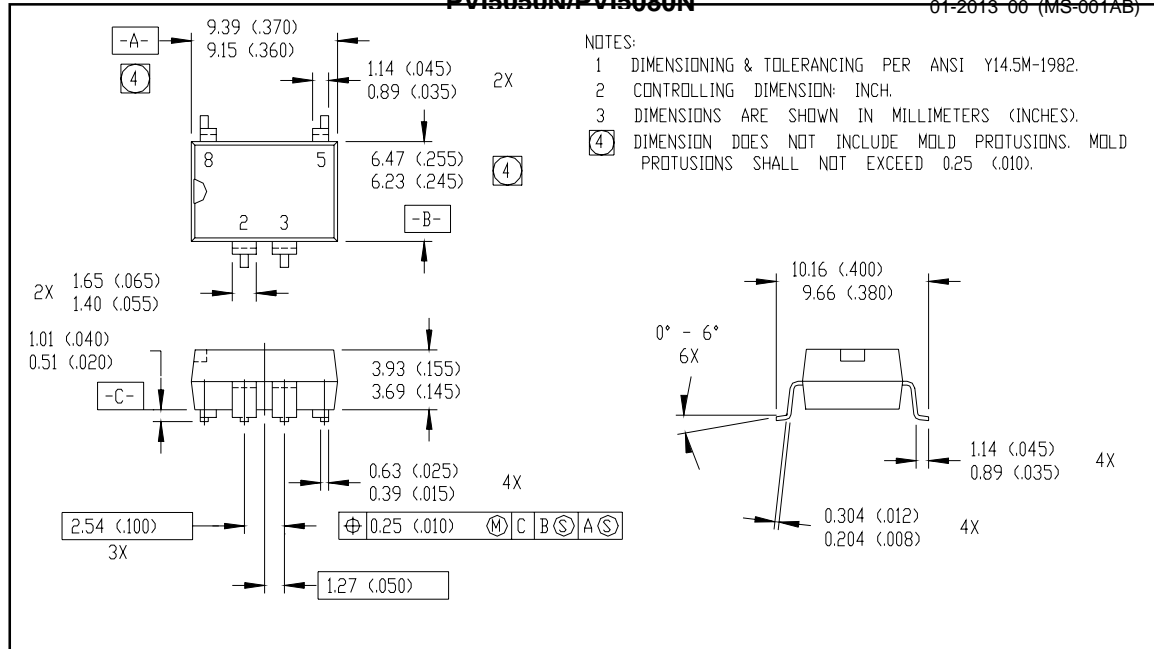


Case Outlines



PVI5050N/PVI5080N

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PVI5050NS/PVI5080NS

01-2019 00